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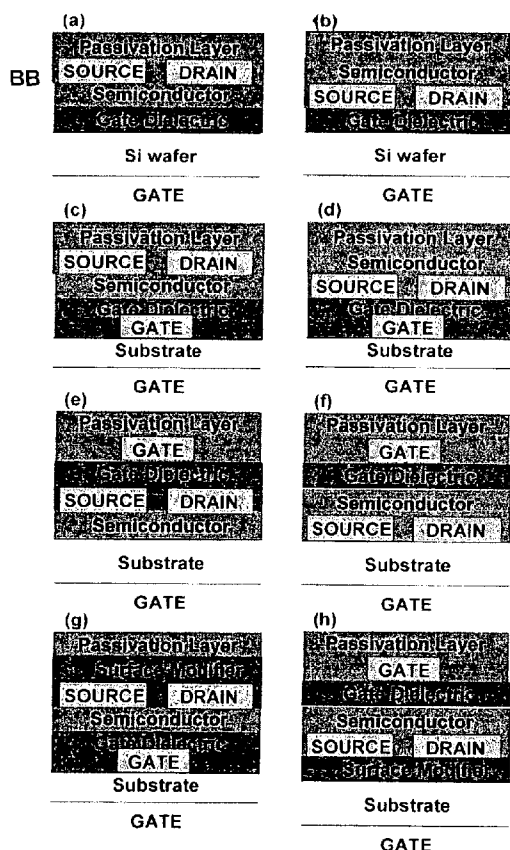
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(54) Title: SOLUTION-PROCESSED INORGANIC FILMS FOR ORGANIC THIN FILM TRANSISTORS



(57) Abstract: A method for fabricating a sol-gel film composition for use in a thin film transistor is disclosed. The method includes fabricating the sol-gel dielectric composition by solution processing at a temperature in the range 60 °C to 225 °C. The sol-gel film made by the method, and an organic thin-film transistor incorporating the sol-gel film are also disclosed.

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